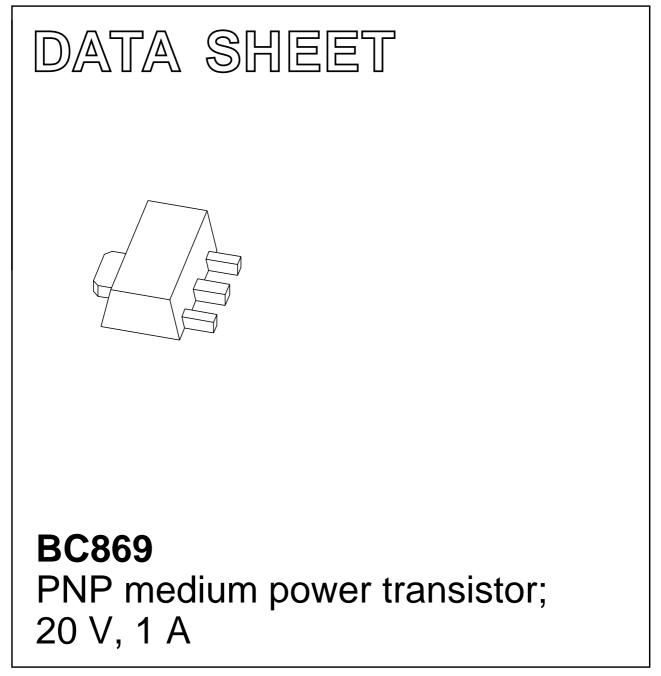
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Apr 08 2003 Dec 02



FEATURES

- High current
- Three current gain selections
- 1.2 W total power dissipation.

APPLICATIONS

- Linear voltage regulators
- High side switch
- Supply line switch
- MOSFET driver
- Audio (pre-) amplifier.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _{CEO}	collector-emitter voltage	-	-20	V
I _C	collector current (DC)	_	-1	А
I _{CM}	peak collector current	-	-2	А
h _{FE}	DC current gain			
	BC869	85	375	-
	BC869-16	100	250	-
	BC869-25	160	375	-

DESCRIPTION

PNP medium power transistor (see "Simplified outline, symbol and pinning" for package details).

PRODUCT OVERVIEW

TYPE NUMBER	PACH	MARKING	
	PHILIPS	EIAJ	WARKING
BC869	SOT89	SC-62	CEC
BC869-16	SOT89	SC-62	CGC
BC869-25	SOT89 SC-62		СНС

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

			PINNING		
TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PIN	DESCRIPTION		
BC868		1	emitter		
		2	collector		
	Bottom view MAM297	3	base		

RELATED PRODUCTS

TYPE NUMBER	DESCRIPTION	FEATURES	
BC868	NPN medium power transistor	NPN complement	
BCP69	PNP medium power transistor	SOT223, 20 V	
B3P369	PNP medium power transistor	SOT54, 20 V	

ORDERING INFORMATION

		PACKAGE				
	NAME	DESCRIPTION	VERSION			
BC868	_	plastic surface mounted package; collector pad for good heat transfer; 3 leads	SOT89			
BC868-16	_	plastic surface mounted package; collector pad for good heat transfer; 3 leads				
BC868-25	_	plastic surface mounted package; collector pad for good heat transfer; 3 leads				

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

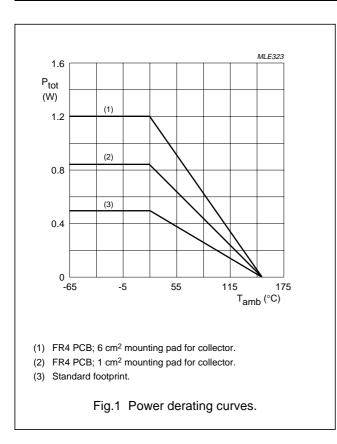
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	-32	V
V _{CEO}	collector-emitter voltage	open base	-	-20	V
V _{EBO}	emitter-base voltage	open collector	_	-5	V
I _C	output current (DC)		_	-1	mA
I _{CM}	peak collector current		_	-2	mA
I _{BM}	peak collector current		-	-200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
		notes 1 and 2	_	0.5	W
		notes 1 and 3	_	0.85	W
		notes 1 and 4	_	1.2	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Refer to SOT89 standard mounting conditions.
- 2. Device mounted on an FR4 printed-circuit board, single-sided copper, tinplated footprint.
- 3. Device mounted on an FR4 printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm².
- 4. Device mounted on an FR4 printed-circuit board, single-sided copper, tinplated, mounting pad for collector 6 cm².

BC869

PNP medium power transistor; 20 V, 1 A



THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	$T_{amb} \le 25 \ ^{\circ}C$		
		notes 1 and 2	250	K/W
		notes 1 and 3	147	K/W
		notes 1 and 4	104	K/W
R _{th(j-s)}	thermal resistance from junction to solder point	$T_{amb} \le 25 \ ^{\circ}C$	20	K/W

Notes

- 1. Refer to SOT89 standard mounting conditions.
- 2. Device mounted on an FR4 printed-circuit board, single-sided copper, tinplated footprint.
- 3. Device mounted on an FR4 printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm².
- 4. Device mounted on an FR4 printed-circuit board, single-sided copper, tinplated, mounting pad for collector 6 cm².

BC869

PNP medium power transistor; 20 V, 1 A

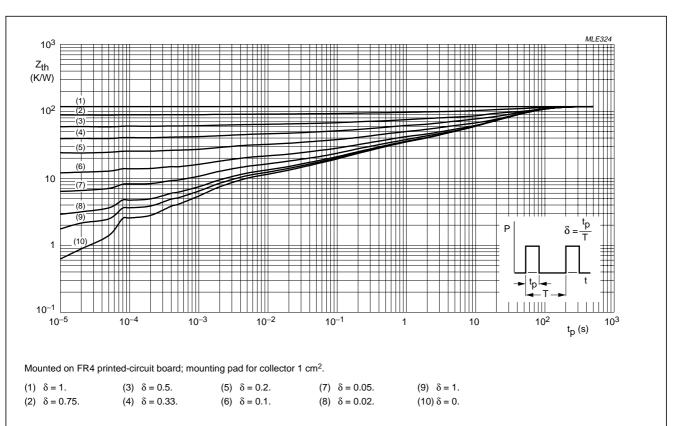
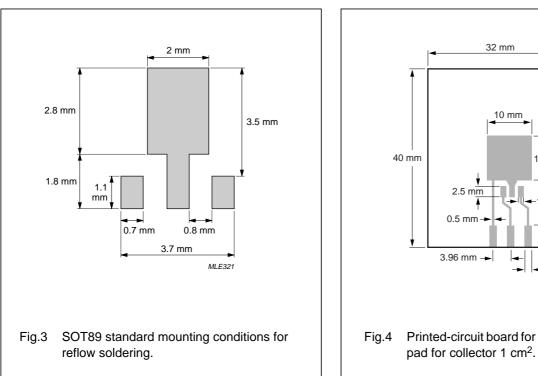
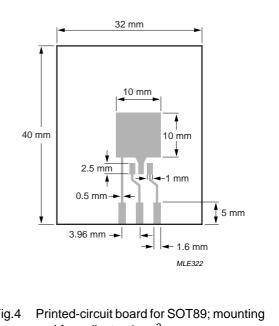


Fig.2 Thermal impedance curves for device mounted on a printed-circuit board with 1 cm² mounting pad.



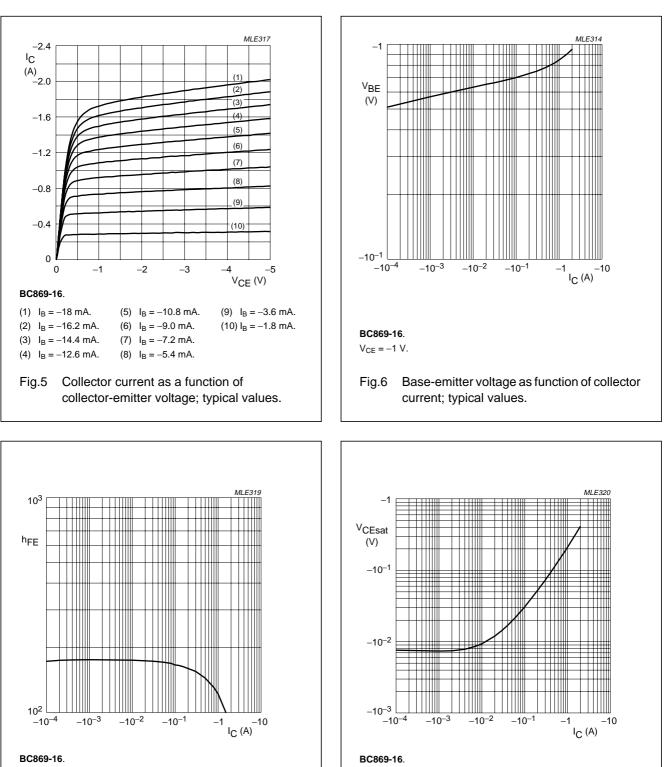


BC869

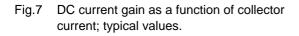
CHARACTERISTICS

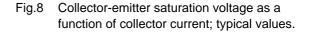
 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -25 \text{ V}; I_E = 0$	-	-	-100	nA
		$V_{CB} = -25 \text{ V}; I_E = 0$	_	-	-10	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0$	-	-	-100	nA
h _{FE}	DC current gain	BC869				
		$V_{CE} = -10 \text{ V}; \text{ I}_{C} = -5 \text{ mA}$	50	-	-	
		$V_{CE} = -1 \text{ V}; I_{C} = -500 \text{ mA}$	85	-	375	
		$V_{CE} = -1 V; I_C = -1 A$	60	-	-	
h _{FE}	DC current gain	$V_{CE} = -1 \text{ V}; \text{ I}_{C} = -500 \text{ mA}$				
		BC869–16	100	-	250	
		BC869–25	160	-	375	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C} = -1$ A; $I_{\rm B} = -100$ mA	-	-	-500	mV
V _{BE}	base-emitter voltage	$V_{CE} = -10 \text{ V}; \text{ I}_{C} = -5 \text{ mA}$	-	-	-700	mV
V _{BE}	base-emitter voltage	$V_{CE} = -1 V; I_C = -1 A$	-	-	-1	V
C _c	collector capacitance	$I_E = i_e = 0; V_{CB} = -10 V; f = 1 MHz$	-	28	-	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V}; I_{C} = -50 \text{ mA};$ f = 100 MHz	40	140	-	MHz

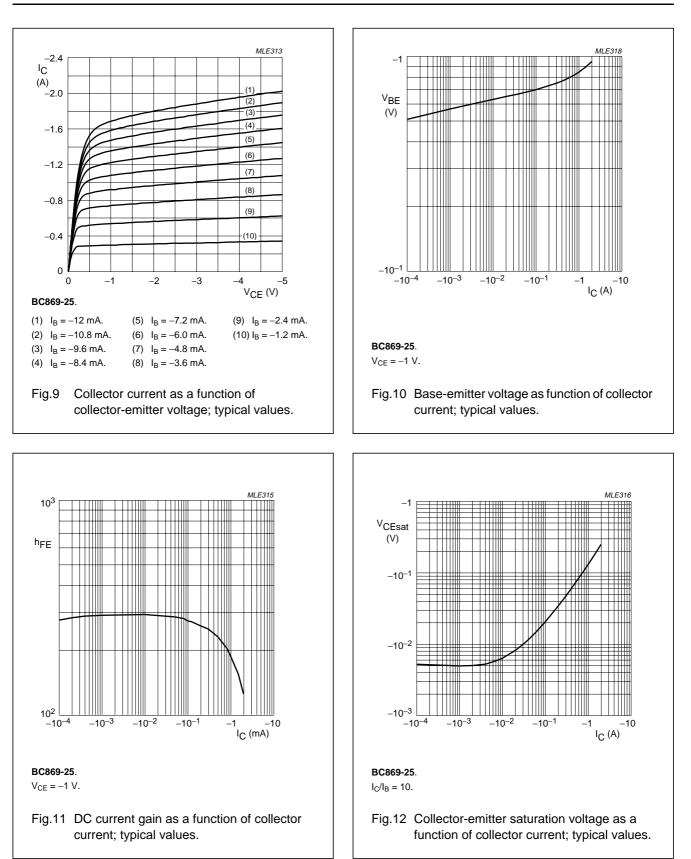


 $V_{CE} = -1 V.$

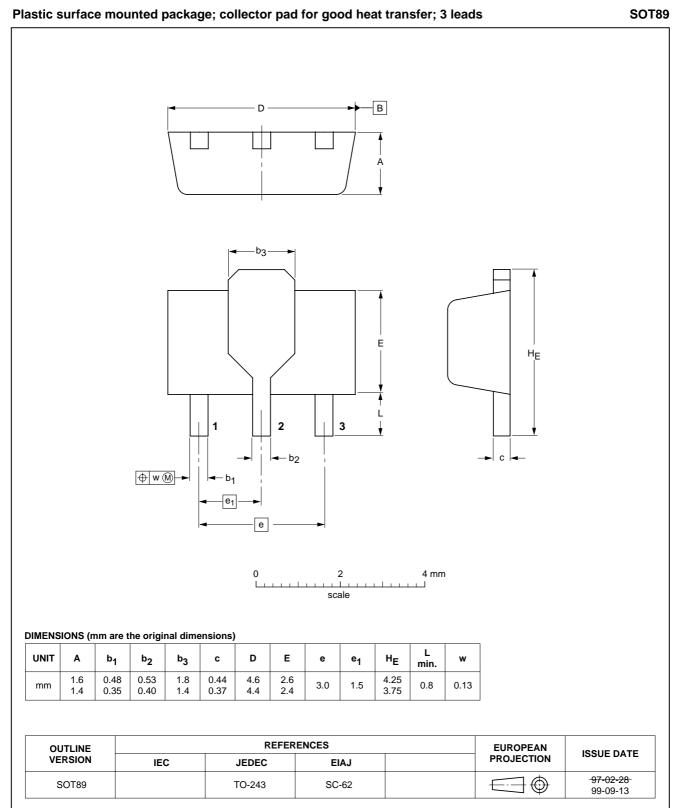




 $I_{\rm C}/I_{\rm B} = 10.$



PACKAGE OUTLINE



BC869

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
1	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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